









# **CEP830G**

#### 500V A 1.2Ω A 5A A SI MOSFET

SILICON Si MOSFET ▲ THT type
N-channel enhancement mode
UL94V-0 rated flame retardant epoxy
TO220-3L package

Super high dense cell density for extremely low R<sub>DS(ON)</sub> **High power and current handling capability** 

### **MAXIMUM RATINGS**

| Parameter (T <sub>C</sub> = 25°C, unless otherwise noted) |                                   | Characteristics |
|---|-----------------------------------|-----------------|
| Drain-Source Voltage                                      | V <sub>DS</sub>                   | 500V            |
| Gate-Source Voltage                                       | V <sub>GS</sub>                   | ±30V            |
| Continuous Drain Current at T <sub>C</sub> = 25°C         | <b>I</b> D                        | 5A              |
| Pulsed Drain Current Note 1                               | I <sub>DM</sub> Note 5            | 20A             |
| Maximum Power Dissipation at T <sub>C</sub> = 25°C        | P <sub>D</sub>                    | 83W             |
| Power Dissipation Derating above 25°C                     | ΔP <sub>D</sub>                   | 0.66W/°C        |
| Operating and Storage Temperature Range                   | T <sub>J</sub> , T <sub>STG</sub> | -55°C to +150°C |

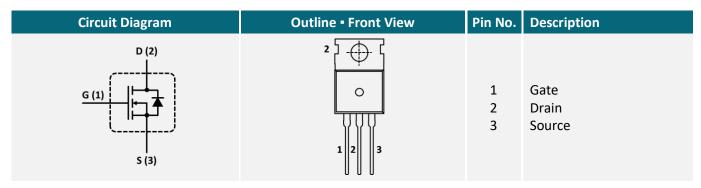
### THERMAL CHARACTERISTICS

| Parameter                               | Symbol             | Limit    |
|---|--------------------|----------|
| Thermal Resistance, Junction-to-Case    | R <sub>TH_JC</sub> | 1.5°C/W  |
| Thermal Resistance, Junction-to-Ambient | R <sub>TH_JA</sub> | 62.5°C/W |

### **APPLICATIONS**

| General Lighting LED & CCFL | Industrial<br>Inverters | Motors<br>& Drives | Power<br>Supplies | UPS |
|-----------------------------|-------------------------|--------------------|-------------------|-----|
| -\                          |                         |                    |                   |     |

#### PIN DESCRIPTION





# **ELECTRICAL CHARACTERISTICS** ▲ T<sub>C</sub> = 25°C, unless otherwise noted

| Item   | Condition   | Symbol              | Min. | Тур. | Max. | Unit |
|--|---|---------------------|------|------|------|------|
| Off Characteristics                                    |   |                     |      |      |      |      |
| Drain-Source Breakdown Voltage                         | $V_{GS} = 0V$ , $I_D = 250\mu A$  | $BV_{DSS}$          | 500  |      |      | V    |
| Zero Gate Voltage Drain Current                        | $V_{DS} = 500V, V_{GS} = 0V$  | I <sub>DSS</sub>    |      |      | 1    | μΑ   |
| Gate Body Leakage Current, Forward                     | $V_{GS} = 30V, V_{DS} = 0V$   | $I_{GSSF}$          |      |      | 100  | nA   |
| Gate Body Leakage Current, Reverse                     | $V_{GS} = -30V, V_{DS} = 0V$  | $I_{GSSR}$          |      |      | -100 | nA   |
| On Characteristics Note 2                              |   |                     |      |      |      |      |
| Gate Threshold Voltage                                 | $V_{GS} = V_{DS}$ , $I_{D} = 250 \mu A$                                 | $V_{GS(th)}$        | 2.5  |      | 4    | V    |
| Static Drain-Source On-Resistance                      | $V_{GS} = 10V, I_D = 2.5A$  | R <sub>DS(ON)</sub> |      | 1.2  | 1.5  | Ω    |
| Dynamic Characteristics Note 3                         |   |                     |      |      |      |      |
| Input Capacitance                                      | $V_{DS} = 25V$ , $V_{GS} = 0V$ , $f = 1MHz$                             | C <sub>ISS</sub>    |      | 595  |      | pF   |
| Output Capacitance                                     | $V_{DS} = 25V$ , $V_{GS} = 0V$ , $f = 1MHz$                             | Coss                |      | 90   |      | pF   |
| Reverse Transfer Capacitance                           | $V_{DS} = 25V$ , $V_{GS} = 0V$ , $f = 1MHz$                             | $C_{RSS}$           |      | 20   |      | pF   |
| Switching Characteristics Note 3                       |   |                     |      |      |      |      |
| Turn-On Delay Time                                     | $V_{DD}$ = 250V, $V_{GS}$ = 10V, $I_D$ = 4A, $R_{G(ext)}$ = 14 $\Omega$ | $t_{D(ON)}$         |      | 15   |      | ns   |
| Turn-On Rise Time                                      | $V_{DD}$ = 250V, $V_{GS}$ = 10V, $I_D$ = 4A, $R_{G(ext)}$ = 14 $\Omega$ | t <sub>R</sub>      |      | 14   |      | ns   |
| Turn-Off Delay Time                                    | $V_{DD}$ = 250V, $V_{GS}$ = 10V, $I_D$ = 4A, $R_{G(ext)}$ = 14 $\Omega$ | t <sub>D(OFF)</sub> |      | 30   |      | ns   |
| Turn-Off Fall Time                                     | $V_{DD}$ = 250V, $V_{GS}$ = 10V, $I_D$ = 4A, $R_{G(ext)}$ = 14 $\Omega$ | t <sub>F</sub>      |      | 10   |      | ns   |
| Total Gate Charge                                      | $V_{DS}$ = 400V, $V_{GS}$ = 10V, $I_D$ = 4A                             | $Q_{G}$             |      | 13   |      | nC   |
| Gate Source Charge                                     | $V_{DS} = 400V$ , $V_{GS} = 10V$ , $I_{D} = 4A$                         | $Q_{GS}$            |      | 2.5  |      | nC   |
| Gate Drain Charge                                      | $V_{DS} = 400V$ , $V_{GS} = 10V$ , $I_D = 4A$                           | $Q_{GD}$            |      | 5    |      | nC   |
| Drain-Source Diode Characteristics and Maximum Ratings |   |                     |      |      |      |      |
| Drain-Source Diode<br>Forward Current                  |   | Is                  |      |      | 5    | Α    |
| Drain-Source Diode<br>Forward Voltage Note 2           | $V_{GS} = 0V$ , $I_S = 3.1A$  | $V_{SD}$            |      |      | 1.6  | V    |

#### Notes

- 1: Repetitive Rating: Pulse width limited by maximum junction temperature
- 2: Pulse Test: Pulse Width ≤ 300µs, Duty Cycle ≤ 2%.
- 3: Guaranteed by design, not subject to production testing.
- 4: Limited only by maximum temperature allowed.
- 5: Pulse width limited by safe operating area.



#### REFERENCE DATA A TYPICAL DEVICE PERFORMANCE

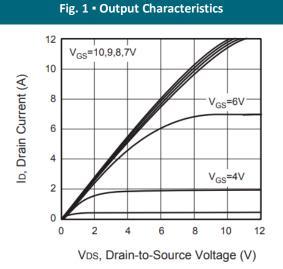
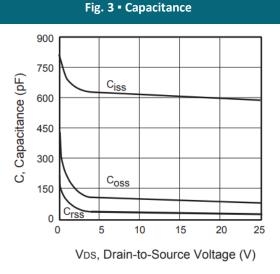
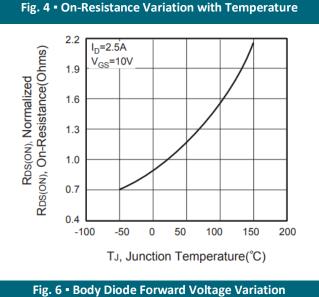
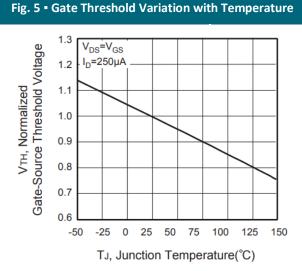
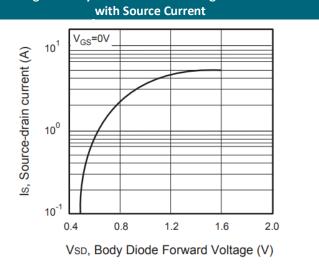


Fig. 2 • Transfer Characteristics









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#### REFERENCE DATA A TYPICAL DEVICE PERFORMANCE

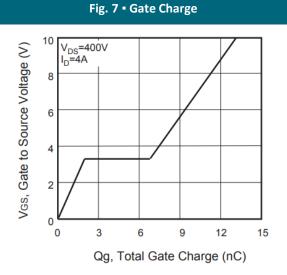


Fig. 8 • Maximum Safe Operating Area

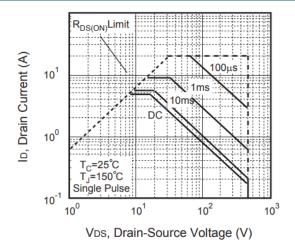
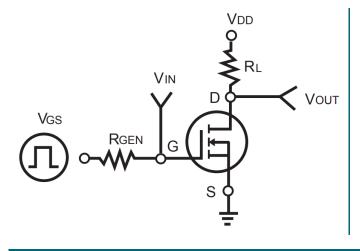


Fig. 9 • Switching Test Circuit

Fig. 10 • Switching Waveforms



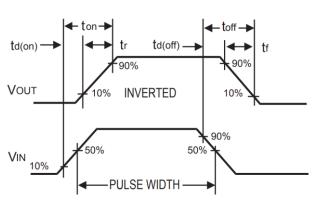
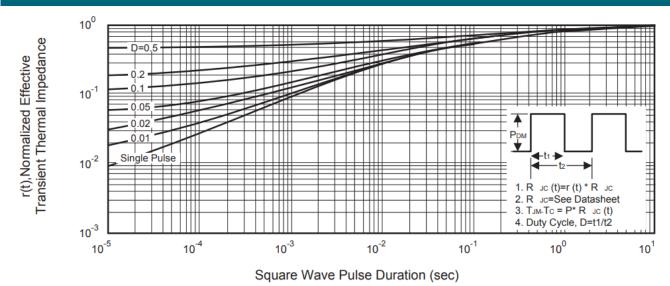


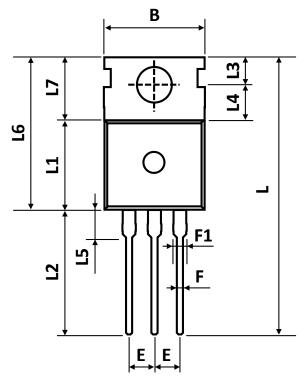
Fig. 11 - Normalized Thermal Transient Impedance Curve

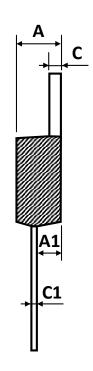


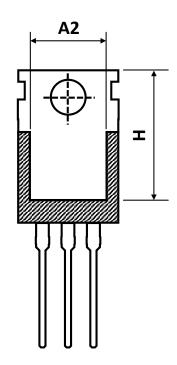
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## **PACKAGE OUTLINE**







| Sym | Millimeters (Min.) | Millimeters (Typ.) | Millimeters (Max.) |
|-----|--------------------|--------------------|--------------------|
| Α   | 4.43               | 4.53               | 4.63               |
| A1  | 2.30               | 2.40               | 2.50               |
| A2  | 7.70               | 7.90               | 8.10               |
| В   | 9.80               | 10.00              | 10.20              |
| С   | 1.25               | 1.30               | 1.40               |
| C1  | 0.45               | 0.50               | 0.60               |
| D   | 3.45               | 3.60               | 3.70               |
| E   | 2.45               | 2.54               | 2.60               |
| F   | 0.70               | 0.80               | 0.95               |
| F1  | 1.15               | 1.33               | 1.50               |
| L   | 26.80              | 28.80              | 30.80              |
| L1  | 9.20               | 9.30               | 9.40               |
| L2  | 12.80              | 13.10              | 13.40              |
| L3  | 2.70               | 2.80               | 2.90               |
| L4  | 3.50               | 3.70               | 3.80               |
| L5  | 2.60               | 2.90               | 3.20               |
| L6  | 15.40              | 15.80              | 16.20              |
| L7  | 6.20               | 6.50               | 6.80               |
| Н   | 12.95              | 13.25              | 13.55              |

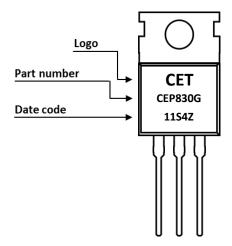
# **ORDERING INFORMATION**

| Part Number | Package   | Packing | Tube Qty. | Inner Box Qty. | Outer Box Qty. |
|-------------|-----------|---------|-----------|----------------|----------------|
| CEP830G     | TO-220-3L | Tube    | 50pcs     | 1,000pcs       | 4,000pcs       |

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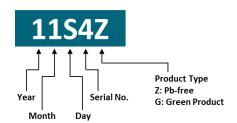


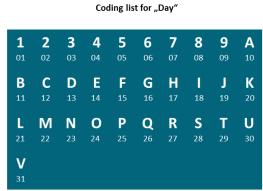
#### **PART MARKING**



#### **DATE CODE**

Example: 11S4Z

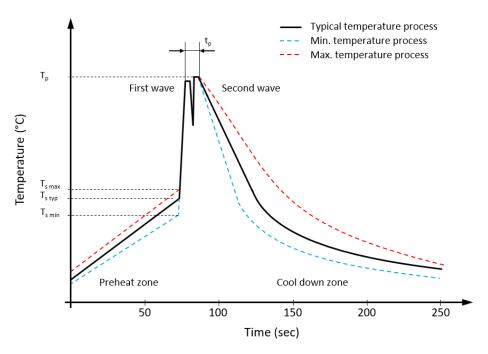








### RECOMMENDED WAVE SOLDERING PROFILE A THT PACKAGE



## Classification wave soldering profile ▲ Refer to EN 61760-1: 2006

| Profile Features                                 |                    | Value ▲ Sn-Pb Assembly                  | Value ▲ Pb-free Assembly                   |
|--|--------------------|---|--|
| Preheat temperature min.                         | $T_{smin}$         | 100 °C                                  | 100 °C                                     |
| Preheat temperature typical                      | T <sub>s typ</sub> | 120 °C                                  | 120 °C                                     |
| Preheat temperature max.                         | $T_{smax}$         | 130 °C                                  | 130 °C                                     |
| Preheat time $t_s$ from $T_{smin}$ to $T_{smax}$ | ts                 | 70 seconds                              | 70 seconds                                 |
| Peak temperature                                 | $T_p$              | 235 °C to 260 °C                        | 245 °C to 260 °C                           |
| Time of actual peak temperature                  | t <sub>p</sub>     | Max. 10 seconds Max. 5 second each wave | Max. 10 seconds<br>Max. 5 second each wave |
| Ramp-down date min.                              |                    | ~ 2 °C/second                           | ~ 2 °C/second                              |
| Ramp-down rate typical                           |                    | ~ 3.5 °C/second                         | ~ 3.5 °C/second                            |
| Ramp-down rate max.                              |                    | ~ 5 °C/second                           | ~ 5 °C/second                              |
| Time 25°C to 25°C                                |                    | 4 minutes                               | 4 minutes                                  |



#### **REVISION TABLE**

| Revision | Date       | Status          | Notes               |
|----------|------------|-----------------|---------------------|
| 001      | 30/09/2022 | Initial release | Initial publication |
|          |            |                 |                     |
|          |            |                 |                     |
|          |            |                 |                     |
|          |            |                 |                     |
|          |            |                 |                     |

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